

# **B140HB**

# SURFACE MOUNT SCHOTTKY BARRIER DIODES

# VOLTAGE RANGE: 40V CURRENT: 1.0 A

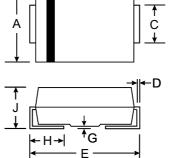
#### Features

- Ultra-low Leakage Current
- Guard Ring Die Construction for
- Transient Protection
  Ideally Suited for Autom
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Plastic Material: UL Flammability Classification Rating 94V-0

## **Mechanical Data**

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)





В

| SMB(DO-214AA)        |      |      |  |
|----------------------|------|------|--|
| Dim                  | Min  | Max  |  |
| Α                    | 3.30 | 3.94 |  |
| в                    | 4.06 | 4.70 |  |
| С                    | 1.91 | 2.21 |  |
| D                    | 0.15 | 0.31 |  |
| Е                    | 5.00 | 5.59 |  |
| G                    | 0.10 | 0.20 |  |
| н                    | 0.76 | 1.52 |  |
| J                    | 2.00 | 2.62 |  |
| All Dimensions in mm |      |      |  |

## Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic   | Symbol                                     | B140HB                       | Unit |
|--|--|------------------------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage @ k = 0.1mA   | V <sub>RRM</sub><br>V <sub>RWM</sub><br>VR | 40                           | V    |
| RMS Reverse Voltage  | V <sub>R(RMS)</sub>                        | 28                           | V    |
| Average Rectified Output Current @ T <sub>T</sub> = 115°C  | Ι <sub>Ο</sub>                             | 1.0                          | А    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine-wave superimposed on rated load  | IFSM                                       | 45                           | А    |
| Non-Repetitive Peak Forward Surge Current<br>5µs Single half sine-wave   | I <sub>FSM</sub>                           | 430                          | А    |
| $ \begin{array}{lll} \mbox{Forward Voltage} & @ \ I_F = 1.0A, \ @ \ T_j = \ 25^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 25^\circ C \\ & @ \ I_F = 1.0A, \ @ \ T_j = \ 125^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 125^\circ C \\ & @ \ I_F = 2.0A, \ @ \ T_j = \ 125^\circ C \\ \end{array} $ | V <sub>FM</sub>                            | 0.53<br>0.70<br>0.49<br>0.64 | V    |
| at Rated DC Blocking Voltage $A = 25^{\circ}C$<br>$T_A = 125^{\circ}C$   | IRM  | 0.1<br>4.0                   | mA   |
| Typical Junction Capacitance (Note 2)  | Cj   | 80                           | pF   |
| Max. Voltage Rate of Change @ Rated VR   | dv/dt                                      | 5300                         | V/µs |
| Typical Thermal Resistance Junction to Terminal (Note 1)   | R <sub>0JT</sub>                           | 36                           | K/W  |
| Operating and Storage Temperature Range  | T <sub>j,</sub> T <sub>STG</sub>           | -55 to +150                  | °C   |

Notes: 1. Thermal Resistance: Junction to terminal, unit mounted on PC board with 5.0 mm<sup>2</sup> (0.013 mm thick) copper pads as heat sink. 2. Measured at 1.0MHz and applied reverse voltage of 5.0V DC.



